
Optimization of the Synthesis Procedures of Graphene and Graphite Oxide

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Abstract

The optimization of both the *chemical vapor deposition (CVD)* synthesis method to prepare graphene and the *Improved Hummers method* to prepare graphite oxide is reported. Copper and nickel were used as catalysts in the CVD-graphene synthesis, CH₄ and H₂ being used as precursor gases. Synthesis variables were optimized according to a *thickness value*, calculated using a homemade Excel-VBA application. In the case of copper, the maximum *thickness value* was obtained for those samples synthesized at 1050°C, a CH₄/H₂ flow rate ratio of 0.07 v/v, a total flow of 60 Nml/min, and a time on stream of 10 min. In the case of nickel, a reaction temperature of 980°C, a CH₄/H₂ flow rate ratio of 0.07 v/v, a total flow of 80 Nml/min, and a time on stream of 1 min were required to obtain a high *thickness value*. On the other hand, the *Improved Hummers method* used in the synthesis of graphite oxide was optimized. The resultant product was similar to that reported in literature in terms of quality and characteristics but both time and cost of the synthesis procedure were considerably decreased.

Keywords: graphene, graphite oxide, CVD, Improved Hummers method, thickness value

1. Introduction

Carbon (C) is a chemical element with atomic number 6 and solid at room temperature. Depending on the synthesis conditions during its growth, carbon can be found in nature with

different allotrope forms [1]. Among them, the softer and the harder materials known in nature are included: graphite (**Figure 1a**) and diamond (**Figure 1b**), respectively. Recently, new carbon allotropes have been discovered such as fullerenes (**Figure 1c**), carbon nanotubes (**Figure 1d**), carbon nanofibers (**Figure 1e**), and carbon nanospheres. To date, the last carbon allotrope that has been appended is graphene (**Figure 1f**). It consists of a two-dimensional (2D) carbon atom network with sp^2 hybridization and only one atom thick [2]. Each atom is bonded by a covalent bond to other three carbon atoms. These carbon atoms are densely packaged in a honeycomb-shape crystal lattice [3] comprising, in turn, of two superimposed triangular subnets [4]. Although graphene has been known since 1960, it was not until 2004 when Andre Geim and Konstantin Novoselov achieved to obtain an isolated graphene sheet using the Scotch[®] tape method [5].

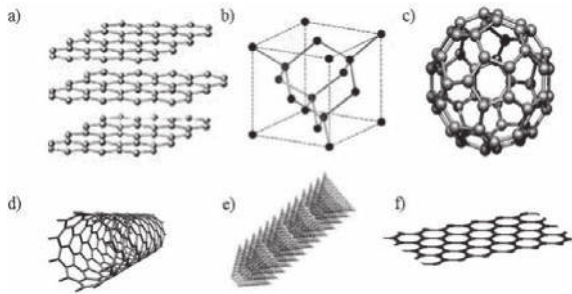


Figure 1. Structure of (a) graphite, (b) diamond, (c) fullerene, (d) carbon nanotube (CNT), (e) carbon nanofiber (CNF), and (f) graphene [6].

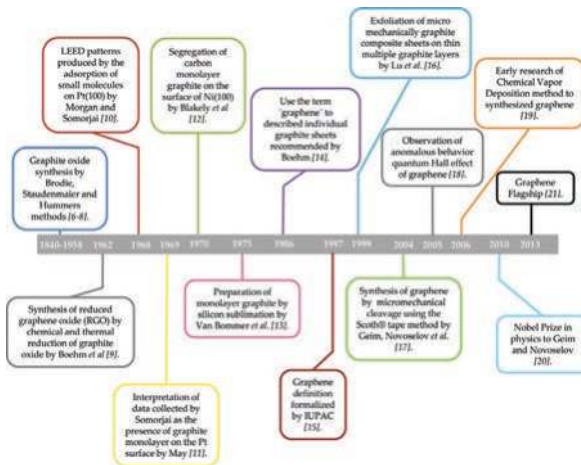


Figure 2. Roadmap of graphene [5, 7–21].

1.1. Graphene chronology

Graphene is one of the most extensively researched materials and is currently regarded as a fascinating material [2]. **Figure 2** shows the chronology of graphene, from 1840 to nowadays.

1.2. Properties and applications

Since 2004, many researchers have been focused on the synthesis of high-yield and high-quality graphene as well as on the search of an easily scalable process to manufacture it [6]. **Table 1** shows the extraordinary properties of graphene related to the applications that can be derived from them.

Property	Application	Ref.
• High-speed electron mobility	Transistors, lasers, photo detectors	[3, 22]
• Large specific surface area	Sensors	[2, 23]
• Conductance		
• Linear band structure (Dirac spectrum for mass less fermions)	Field effect transistors	[5]
• High electrical conductivity	Transparent conductive film	[23]
• High-speed electron mobility		
• High optical transmittance		
• High theoretical surface area	Clean energy devices	[23]
• Electron transfer along 2d surface		
• Anomalous quantum hall effect	Ballistic transistors	[24]
• Irrelevant spin-orbit coupling	Spin-Valve Devices	[22]
• High conductivity	Conductive materials, electrical batteries, super capacitors	[2]
• Easy absorption of gases	Contamination control	[22]
• Transparency (>99%)	Displays, touch screens	[25]
• High electronic conductivity		
• Impermeability	Coatings	[26]
• High mechanical stress (hardness)	Construction	[3]

Table 1. Graphene properties and applications.

1.3. Graphene synthesis

Two different routes can be followed to synthesize graphene: **Bottom Up** and **Top Down** (**Figure 3**). *Bottom-Up* route comprised those methods, which use a carbonaceous gas source to produce graphene. The most relevant ones are *epitaxial growth on Silicon Carbide (SiC)* [27] and *chemical vapor deposition (CVD)* [3]. *Top-Down* route is based on the attack of graphite (used as raw material) to break its layers forming graphene sheets [28]. Methods such as

micromechanical cleavage [5, 22], *exfoliation of graphite intercalation compounds (GICs)* [29], *arc discharge* [30, 31], *unzipping carbon nanotubes (CNTs)* [32, 33], *graphene oxide exfoliation* [27] and *solvent-base exfoliation* [34–37] comprise the *Top-Down* route.

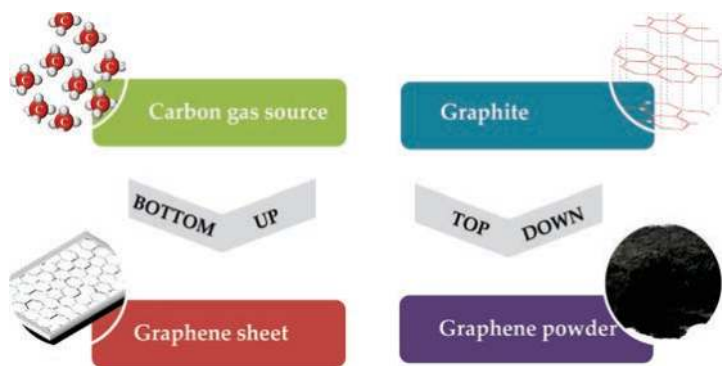


Figure 3. *Bottom-Up* and *Top-Down* routes to synthesize graphene.

Among the different *Bottom-Up* synthesis methods, *CVD* is considered the most extensively one used to synthesize large amounts of high-quality graphene sheets. This method is simple and easily scalable [38]. It is important to highlight that the quality and the type of graphene (monolayer, bilayer, few layer, or multilayer) can be varied as a function of the catalytic metal used [3, 39, 40].

On the other hand, the simultaneous reduction and exfoliation of graphene oxide can be considered, among the different *Top-Down* synthesis methods, the easiest one to synthesize graphene-based powder materials. However, the synthesis of graphite oxide (GrO) is first required since it is the intermediate product leading to graphene oxide from graphite. Graphite oxide synthesis is an exothermic process that involves the use of strong acid solutions. In addition, it can be considered as a tedious procedure because many steps are required before the ultimate product is obtained.

Next, the most relevant results obtained in the *CVD* synthesis of graphene are summarized using nickel and copper as catalytic metals, with particular emphasis on the optimization of the main operating variables (synthesis time, temperature, and amount of gases involved during the synthesis). Similarly, the synthesis of graphite oxide is also described. In the latter case, the optimization study here reported pursued the reduction of the time of preparation and the amount of chemical oxidants used during the synthesis of this intermediate product.

2. Chemical vapor deposition of graphene layers

Chemical vapor deposition (*CVD*) is a *Bottom-Up* technique, which allows to synthesize wafer-scale graphene [41, 42]. In the *CVD* procedure, a metal substrate, which is used as the catalyst,

is placed into a furnace and heated to high temperatures. The heat anneals the metal, increasing its domain size [43]. Nitrogen, a carbon source (such as methane), and hydrogen are flowed through the furnace during the graphene synthesis. Hydrogen catalyzes the reaction produced between the carbon source and the metal substrate resulting in carbon atoms coming from the carbon source decomposition, which are deposited onto the metal surface through chemical absorption [3]. Hydrogen activates the carbon bounds of the metal surface and controls the size and morphology of graphene domains [44]. After the reaction, the furnace is cooled to keep the deposited carbon atom layer from aggregating into bulk graphite, which crystallizes into a contiguous graphene layer on the metal surface [45]. This method has the advantage of producing large size and high-quality graphene layers, and the ability to synthesize graphene at wafer scale [41]. Moreover, it is considered a low-cost method leading to a high yield if compared to other growth methods. However, the CVD graphene tends to wrinkle due to the difference in thermal expansion between graphene and metal layer. This fact could be decreased via proper annealing [43]. Nickel and copper are commonly used in the CVD method as the metal substrate material for graphene synthesis [46]. Other transition metals such as Ru, Co, and Pt are alternative transition metals, although they are used less frequently [47, 48].

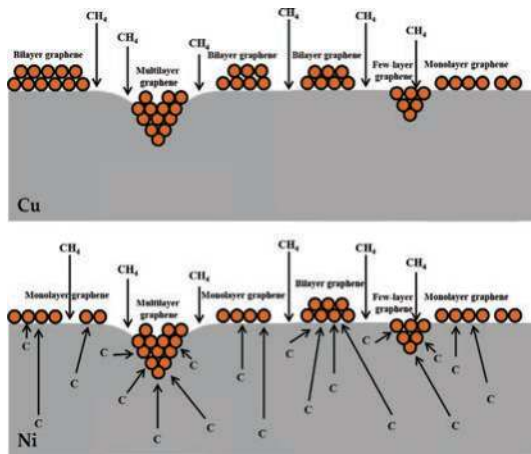


Figure 4. CVD growth-mechanism graphene on copper and nickel sheets [50].

Depending on the metal used, two different mechanisms can be differentiated in the CVD-graphene synthesis (**Figure 4**). The first one, called *Carbon atoms surface deposition*, which is the growth mechanism observed over copper sheets, is described like the direct deposition of carbon atoms on the catalyst surface. In the second one, called *Carbon atoms surface segregation*, which is the growth mechanism observed when nickel is used as the catalyst, carbon atoms decomposed from the carbonaceous source are diffused onto the catalyst bulk during the annealing step at high temperatures. Then, they precipitate on the catalyst during the cooling period [49].

2.1. Optimization of the CVD operational parameters

Several studies have established a close correlation between the CVD growth parameters, the quality of the graphene obtained, and the number of graphene layers, leading to the formation of different types of graphene (named as monolayer, bilayer, few layer, and multilayer) on the metal substrate [51–55].

Zhang et al. [51] and Nie et al. [52] found that the graphene quality improved at higher temperatures of reaction. On the contrary, lower temperatures gave rise to graphene with a number of defects. Rybin et al. reported that the larger the temperature of reaction, the higher the amount of atoms dissolved into the metal layer, leading to the production of more and more graphene layers [53].

Recent studies have showed that the concentration of hydrogen, which is obviously related with the CH_4/H_2 flow rate ratio and the total flow rate of CH_4 and H_2 during the reaction step, also plays an important role in providing quality to CVD graphene. Gao et al. found for an atmospheric pressure CVD system that high hydrogen concentrations contributes to the degradation of the graphene quality as a result of the occurrence of defects and wrinkles [54]. In a similar way, Vlasiouk et al. detected the presence of a critical value of the partial hydrogen that determines the occurrence of graphene growth (<2 Torr with 30 ppm of CH_4). No graphene nucleation was observed below this value, whereas higher hydrogen concentrations caused degradation in graphene quality [44]. Finally, several groups have shown that the growth of bilayer and few-layer graphene depends on the concentration of active carbon species [55], which was in turn related with the CH_4/H_2 flow ratio and the total flow rate of CH_4 and H_2 used during the reaction step.

On the other hand, monocrystalline metals favor the formation of superficial and uniform monolayer, and bilayer graphene, being hindered the formation of multilayer graphene due to graphene, is grown over smooth and free defect surfaces (**Figure 4**). However, the industrial production of graphene strongly recommends to use polycrystalline metals, since it is much lower than that of monocrystalline one [56].

Figure 5a shows the experimental installation used for CVD-graphene synthesis over polycrystalline metals (Ni and Cu). **Figure 5b** shows the stages followed during the graphene synthesis as well the duration, temperature, and gases used in each of them.

Methane and hydrogen were actually used as precursor gases. Graphene samples were grown by CVD at atmospheric pressure on 25- μm -thick polycrystalline metal foils in a 40-inch quartz tube heated in a furnace. Firstly, the reduction step was carried out by heating the furnace to 900°C, passing through the tube a flow of N_2 (400 sccm) and H_2 (100 sccm) to prevent metal sheet oxidation. The annealing step was carried out by maintaining the furnace at this temperature for 45 min. Later, the reaction step was started and carried out at different operational conditions in order to improve the quality of the obtained graphene by decreasing the amount of multilayer graphene formed over the metal. The temperature set point was increased and varied in the range of 900–1050°C. A ratio of methane to hydrogen in the range 0.4–0.07 v/v was introduced into the reactor for different times (15 min to 30 s) to complete the

reaction step. The total flow of gases involved during the reaction step ranged from 80 to 100 Nml/min. Finally, the system was cooled down ($10^{\circ}\text{C min}^{-1}$) by flowing 400 sccm of nitrogen.

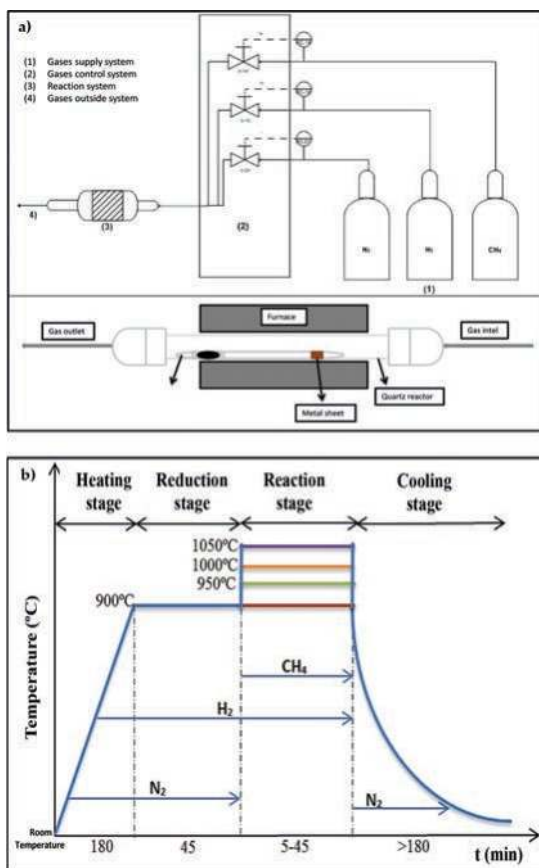


Figure 5. (a) Experimental installation for CVD graphene synthesis. (b) Summary of the CVD-graphene synthesis steps and conditions.

To control the graphene thickness and determine the percentage of each type of graphene (monolayer, bilayer, few layer, and multilayer) deposited over the polycrystalline metal foils, a homemade Excel-VBA application was designed. This software used the different colors present in a digitalized optical microscope image to evaluate the percentage of the different types of graphene deposited over the metal sheets. By using Raman spectroscopy, the

relationship between the different colors present in optical images has been demonstrated with each type of graphene [3]. For this purpose, a logarithmic scale was considered in the Excel-VBA software design. Thus, *thickness values* 1, 10, 100, and 1000 were assigned when the 100% of the sample was covered by multilayer, few-layer, bilayer, and monolayer graphene, respectively. The *thickness value* was calculated as an average of the percentage obtained for each type of graphene calculated by the Excel-VBA application.

Ferrari et al. [57] demonstrated that using the second-order 2D feature obtained in the Raman spectra, it was possible to know the number of graphene layers. Based on that study, Malard et al. [58] investigated the theoretical background associated with the double-resonance Raman-scattering mechanism that gives rise to the main feature in the Raman spectra of the different types of graphene. Thus, the deconvolution of the 2D peak, corresponding to each type of graphene, showed that in the case of monolayer graphene the 2D peak could be fitted with a symmetric single peak only; in the case of bilayer graphene, the 2D peak could be deconvoluted in four different contributions; in the case of few-layer and multilayer graphene, the 2D peak could be deconvoluted in two contributions, which is characteristic of graphite (material consisting of many layers of graphene) (Figure 6).

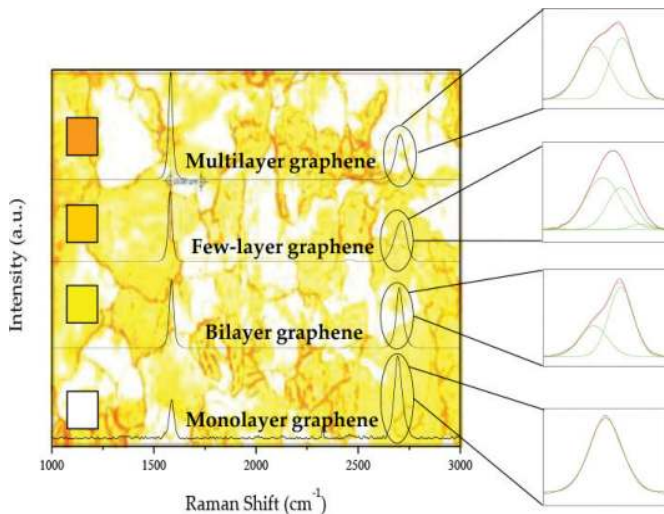


Figure 6. Relationship between optical microscope image and typical Raman spectra of monolayer [48, 59–61], bilayer [47, 59, 60, 62], few layer [63–65], and multilayer [63, 64] graphene.

In this study, polycrystalline copper and nickel were chosen as metal catalyst in the synthesis of CVD graphene.

Regarding polycrystalline Cu, 1050°C was required to maximize the amount of monolayer graphene over the metal, whereas 980°C was selected as the optimum reaction temperature in the case of using polycrystalline nickel. In the former case, the *thickness value* was found to be

4.2, the proportion of each type of graphene being the following one: 81% multilayer graphene, 17% few-layer graphene, and 2% bilayer graphene; the presence of monolayer graphene was considered negligible. In the latter case, the *thickness value* was found to be 397, in turn the proportion of each type of graphene being the following one: 0.9% multilayer graphene, 40% few-layer graphene, 22% bilayer graphene, and 37% monolayer graphene.

Regarding the CH₄/H₂ flow rate ratio, an optimal value of 0.07 v/v was obtained when both metals were used as catalysts. A *thickness value* of 34.7 was obtained using Cu (20% multilayer graphene, 20% few-layer graphene, and 51% bilayer graphene), whereas a *thickness value* of 536 was obtained using Ni (0.5% multilayer graphene, 27% few-layer graphene, 20% bilayer graphene, and 52% monolayer graphene).

Finally, regarding the study of the influence of the total flow of gases (CH₄+ H₂) and reaction time, it could be concluded that the best results in the case of using Cu as the catalyst were obtained for a total gas flow of 60 Nml/min and a reaction time of 10 min, leading to an increased *thickness value* of 60, 56 and 11% of the resulting sample being covered by bilayer graphene and multilayer graphene, respectively. In the case of using Ni as the catalyst, the best results were obtained for a total gas flow of 80 Nml/min and a reaction time of 1 min (*thickness value* of 810). At these conditions, just 0.3% of the sample was covered by multilayer graphene, 11% by few-layer graphene, 9% by bilayer graphene, and 80% by monolayer graphene.

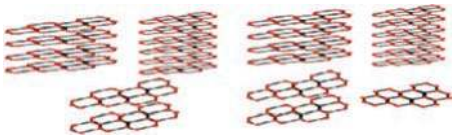
Variable	Copper	Nickel
Reaction temperature (°C)	1050	980
CH ₄ /H ₂ flow rate ratio (v/v)	0.07	0.07
Total gas flow (CH ₄ +H ₂) during reaction step	60	80
Reaction time (min)	10	1
Graphene type		
Thickness value	59	810

Table 2. Optimum synthesis conditions.

Summarizing, the *thickness value* was increasing at each stage of the optimization study regardless of the metal used. However, it was not possible to detect monolayer graphene on polycrystalline copper foil. In the case of using polycrystalline nickel, monolayer graphene covered 80% of the foil for the optimal conditions of synthesis.

Table 2 shows the optimum operating conditions for each metal resulting from this study.

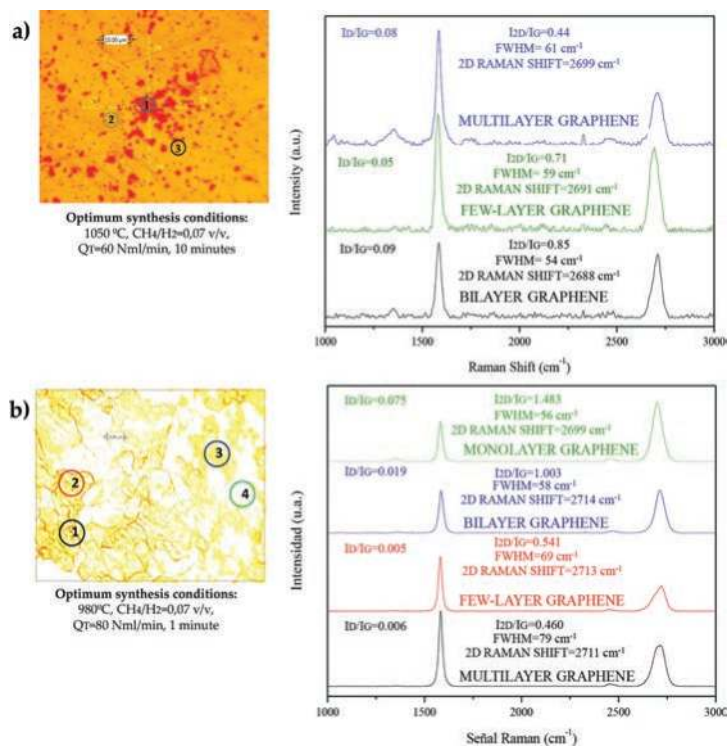


Figure 7. Raman spectra corresponding to graphene samples synthesized using (a) copper and (b) nickel.

Figure 7 shows the Raman spectra corresponding to the graphene samples obtained at the optimal conditions. D peak (1350 cm^{-1}) is related to the presence of defects in graphitic materials [66]. G peak ($\sim 1560\text{ cm}^{-1}$) denotes the symmetry of graphite band and is a way of checking the vibration of sp^2 -hybridized carbon atoms in the same plane. Finally, 2D peak, visible around 2700 cm^{-1} , is the hallmark of graphene layers [67]. The relationship between the intensity of D and G peak (I_D/I_G) is a way to check the amount of defects present in the graphene sheet. The number of graphene layer is also related to the ratio between the intensity of 2D and G peak (I_{2D}/I_G). 2D peak position in graphene sample should be displaced to lower Raman shift values in comparison with that of graphite. Finally, full width at half maximum (FWHM) is related to the lifetime of the excited states and is calculated as the Raman shift difference to the half average height of the 2D peak [39]. For both metal catalysts, the I_D/I_G ratio values were low, demonstrating that graphene samples had low amount of defects, whereas the I_{2D}/I_G ratio values increased, as expected, from multilayer to monolayer graphene [68]. The contrary effect could be observed for the FWHM parameter, which decreased from multilayer to monolayer graphene. Finally, 2D peak position was, in all cases, located at around 2700 cm^{-1} , which is characteristic of graphene materials [3, 39].

3. Graphite oxide

Graphite oxide (GrO) can be defined as a set of functionalized graphene sheets that are mainly composed of carbon, oxygen, and hydrogen atoms. This material is considered a precursor of graphene itself [69]. The structure of graphite oxide is similar to that of graphite differing only in the oxygenated groups present in GrO, which give rise to a greater distance between the graphene layers [69]. GrO consists of a hexagonal network of sp^2 - and sp^3 -hybridized carbon atoms that bear hydroxyl and epoxide functional groups on the 'basal' plane and carboxyl and carbonyl groups at the edges [70].

3.1. Graphite oxide synthesis

Graphite oxide can be synthesized by the Brodie [7], Staudenmaier [8], or Hummers and Offeman [9] methods or by variations of the latter, namely *Modified Hummers method* or *Improved Hummers method* [71]. The main differences between the abovementioned methods are summarized in **Table 3**, with particular emphasis on the nature of the oxidant, the toxicity, and the main advantages or disadvantages of each approach.

3.2. Improved Hummers method

In 1958, Hummers reported the most popular procedure to synthesize graphite oxide, which is based on the oxidization of graphite by using $KMnO_4$ and $NaNO_3$ in concentrated H_2SO_4 [9]. However, this method yields NO_x and is dangerous itself due to the constant explosions, which take place during the synthesis [71]. In 2010, Marcano et al. [71] reported an improved synthesis based on the Hummers method by using graphite flakes as the raw material. Graphite oxide synthesized from graphite flakes can be easily soaked and dispersed in water and could be used as the precursor for different applications due to its hydrophilic character. They detected that an improved graphite oxide with fewer defect in the basal plane can be prepared using $KMnO_4$ as oxidation agent and a 9:1 mixture of concentrated H_2SO_4 and H_3PO_4 . They also reported that graphite oxide synthesized with this *Improved Hummers method* provided a greater amount of hydrophilic-oxidized graphite, likewise having a more regular structure with a greater amount of basal plane framework retained. Raman and infrared spectroscopy results indicated that graphite oxide samples obtained through both methods were almost similar, both of them showing the characteristics D and G peaks that confirmed the lattice distortion in Raman spectroscopy. FTIR-ATR spectra also confirmed the presence of functional groups. In addition, atomic force microscopy (AFM) showed that the thickness of both graphite oxides was around 1.1 nm. They confirmed with a large variety of methods, such as thermogravimetry analysis (TGA), solid-state colossal magnetoresistance (CMR), X-ray diffraction (XRD), and X-ray photoelectron spectroscopy (XPS), that graphite oxide synthesized with the *Improved Hummers method* was, if it is compared to that produced from the Hummers one, a more oxidized material, presented a more organized structure, and contained both more epoxide functionalities, and more regular carbon framework.

Brodie Method	Staudenmaier Method	Hummers Method	Modified Hummers Method	Improved Hummers Method
<p>Oxidants: KClO₃, HNO₃</p> <p>Toxicity: Yes</p> <p>Disadvantages:</p> <ul style="list-style-type: none"> •Weak Toxicity. •Soft dispersibility in basic solutions. •Small size, limiting thickness and providing an imperfect structure. 	<p>Oxidants: KClO₃, (NaClO₂), HNO₃, H₂SO₄</p> <p>Toxicity: Yes</p> <p>Disadvantages:</p> <ul style="list-style-type: none"> •Time-consuming and dangerous method. •Addition of KClO₃ generally takes longer than a week and CO₂ is evolved, thus making necessary to remove an inert gas. •The risk of explosions is a constant danger. 	<p>Oxidants: KMnO₄, H₂SO₄, NaNO₃</p> <p>Toxicity: No (NO_x)</p> <p>Advantages:</p> <ul style="list-style-type: none"> •Higher oxidation degree than that obtained in Brodie or Staudenmaier Methods. <p>Disadvantages:</p> <ul style="list-style-type: none"> •It is still considered that the oxidation is incomplete. 	<p>Oxidants: KMnO₄, H₂SO₄, NaNO₃</p> <p>Toxicity: No (NO_x)</p> <p>Advantages:</p> <ul style="list-style-type: none"> •Improved level of oxidation and, therefore, product performance. <p>Disadvantages:</p> <ul style="list-style-type: none"> •Separation and purification processes are tedious. •Highly time-consuming. 	<p>Oxidants: KMnO₄, H₂SO₄, H₃PO₄</p> <p>Toxicity: No</p> <p>Advantages:</p> <ul style="list-style-type: none"> •Defects in the basal plane are reduced. •Larger amount of oxidized graphite is provided. •The degree of reduction provides an equivalent level of conductivity when compared to other methods. •It is a high performance method. •Environmentally friendly, toxic gases are not generated during the preparation. •The product has a more organized structure.

Table 3. Synthesis methods of graphite oxide.

3.3. Optimization of the Improved Hummers method

The most remarkable results obtained in the optimization study of the synthesis of graphite oxide based on the method proposed by Marcano et al. [71] (*Improved Hummers method*) are summarized below. Thus, the objective was to reach the same quality product but using a lesser time-consuming experimental procedure and conducting lower production costs. With this purpose, the different stages of the *Improved Hummers method* used in the synthesis of graphite oxide were optimized. The method consists of the oxidation, in the presence of H₂SO₄ and H₃PO₄, of 3 g of graphite per 9 g of KMnO₄ used as the oxidizing agent in 400 ml of solution. The oxidation step is maintained at 50°C for 12 h. Later, the reaction mixture is washed twice with 200 ml of deionized water, HCl, and ethanol. Finally, the product is coagulated with 200 ml of dry diethyl ether and dried at 100°C [71].

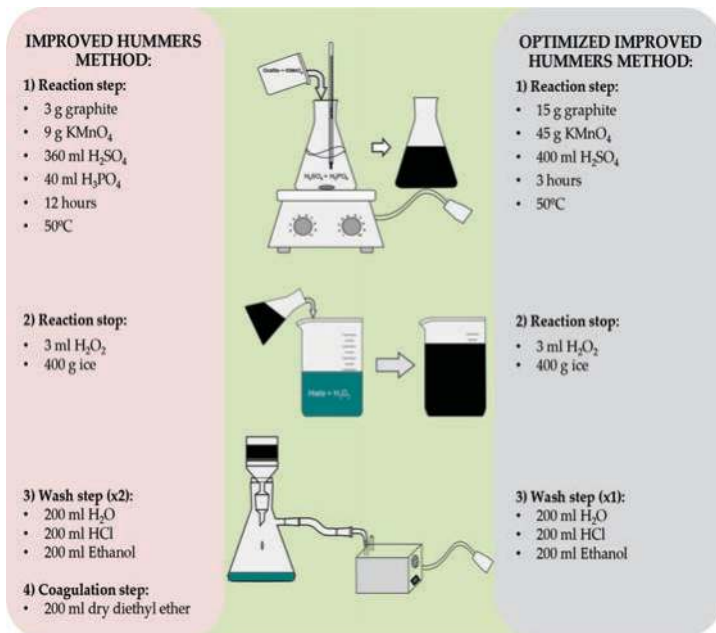


Figure 8. Differences between the *Improved Hummers* and *Optimized Improved Hummers* methods.

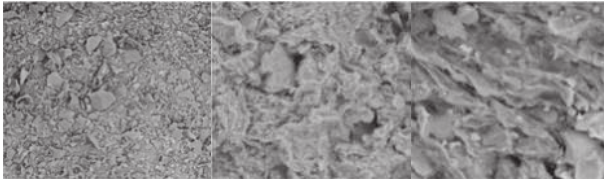
First, the oxidation time, which is the most time-consuming step of the whole synthesis process, was reduced. This way, the oxidation time was reduced from 12 to 3 h, whereas the other synthesis conditions were kept constant without affecting the quality of the final product. The introduction of functional groups, both at the edges and in the basal plane, was achieved in 3 h instead of the 12 h required in the original method.

Second, it was demonstrated that the coagulation step used by Marcano et al. [71] did not significantly influence over the quality and characteristic properties of the final product. Consequently, it was removed from the synthesis procedure.

On the other hand, Marcano et al. used three different products twice during the washing step: deionized water, which was used to reach the pH neutralization; HCl, which was required to remove the remaining metal from the graphite oxide, and ethanol, which was used to achieve a faster drying of the final product. We demonstrated that the quality and characteristic of the final product were not affected at all if the treatment of the cake with these three products was or not repeated. In addition, the elimination of H_3PO_4 in the synthesis procedure was considered. Similarly, this action did not alter the characteristics of the final product.

Finally, a series of tests were conducted in order to increase the amount of graphite that can be treated per batch, without altering the properties of the final product (the raw method

considers 3 g of graphite and 9 g of KMnO_4 in 400 ml of solution). Here, the KMnO_4 /graphite ratio (3:1) was maintained in order to not alter the degree of oxidation. This way, the amount of these materials was progressively increased. It was observed that it was possible to use up to 15 g of graphite (and hence 45 g of KMnO_4) in 400 ml of solution without altering the characteristics and quality of the product. **Figure 8** schematically summarizes the differences between the original method (*Improved Hummers method*) and the optimized one (*Optimized Improved Hummers method*).

		Graphite	Improved Hummers method	Optimized Improved Hummers method
Raman spectroscopy I_D/I_G		0.067	0.726	0.946
DRX	L_a (nm)	263	26.5	20.4
	L_a (nm)	41	9.6	10.1
	L_c (nm)	20	4.7	4.9
	d_{002} (nm)	0.334	0.810	0.910
Elemental composition	N_c	60	5.8	5.4
	C	98.04	48.8	51.4
	O	1.96	48.2	45.1
	S	0.0	0.7	2.8
	Cl	0	0.8	0.6
SEM	Mn	0	1.4	0.1
				
	BET	Surface area (m^2/g)	1.7	22.2
	Total pore volume (cm^3/g)	0.038	0.113	0.129

La: crystal dimension described by layer sized; **Lc:** stack height; **Nc:** number of layers in the stacking structure; **C:** carbon, **O:** oxygen, **S:** sulfur, **Cl:** chlorine; **Mn:** manganese.

Table 4. Characterization results of graphite oxide synthesized using both the *Improved Hummers* and *Optimized Improved Hummers methods*.

Table 4 lists some properties of the graphite oxide samples synthesized by the *Optimized Improved Hummers method* and those prepared from the parent one. I_D/I_G ratio, related with the structural disorder in the graphite network and inversely proportional to the sp^2 cluster average sized [72], considerably increased after graphite oxidation. Crystal dimension (L_a value) decreased after the incorporation of oxygenated groups, which agree with the increase in the structural disorder. In the same way, the number of graphene layers in the stacking

structure (Nc) decreased after the oxidation process [73]. Elemental analysis showed an increase in the percentage of oxygen from graphite to graphite oxide due to the oxidation process. Comparing both graphite oxides, the percentage of each compound (C, O, S, Cl, and Mn) was quite similar [74]. In addition, scanning electron microscope (SEM) images showed an agglomeration of the product after the oxidation process, being several microns in size. Finally, a significant increase in the surface area was observed after graphite oxidation, because of the expansion of graphene layers [75].

The almost similar characterization values of both samples of graphite oxide demonstrated that the optimization process did not affect both quality and structure of the final product.

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